

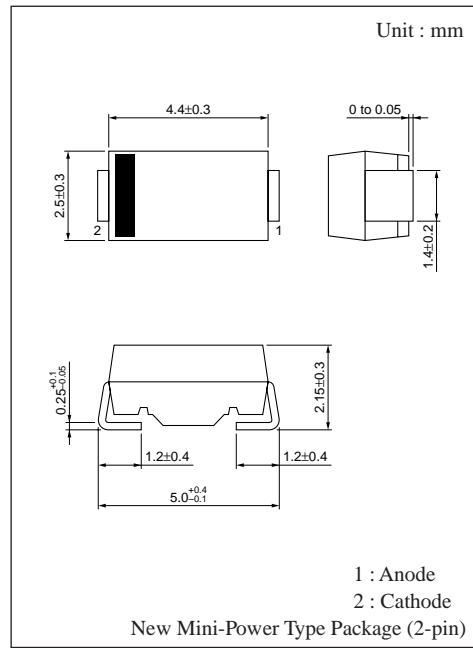
# MA737

## Silicon epitaxial planer type

For high-frequency rectification

### ■ Features

- Forward current (average)  $I_{F(AV)}$  : 1.5A type
- Reverse voltage (DC value)  $V_R$  : 30V
- Automatic insertion possible with emboss taping



Marking Symbol : PC

### ■ Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Rating	Unit
Reverse voltage (DC)	$V_R$	30	V
Repetitive peak reverse voltage	$V_{RRM}$	30	V
Average forward current	$I_{F(AV)}^*$	1.5	A
Non-repetitive peak forward surge current	$I_{FSM}^*$	60	A
Junction temperature	$T_j$	-40 to +125	°C
Storage temperature	$T_{stg}$	-40 to +125	°C

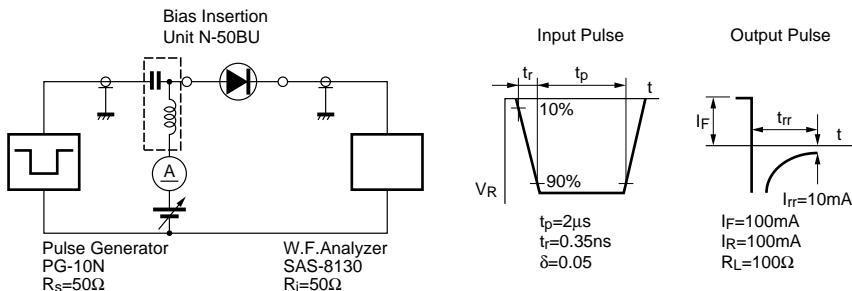
\*1 With a printed-circuit board (copper foil area 2.5mm × 2.5mm +0.8mm – 20mm or more on both cathode and anode sides)

\*2 50Hz sine wave, one-cycle wave, high value (non-repetitive)

### ■ Electrical Characteristics ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Condition	min	typ	max	Unit
Reverse current (DC)	$I_R$	$V_R = 30\text{V}$			1	mA
Forward voltage (DC)	$V_F$	$I_F = 2\text{A}$			0.5	V
Terminal capacitance	$C_t$	$V_R = 10\text{V}, f = 1\text{MHz}$		70		pF
Reverse recovery time	$t_{rr}^*$	$I_F = I_R = 100\text{mA}$ $I_{rr} = 10\text{mA}, R_L = 100\Omega$			50	ns

Note 1. Schottky barrier diode is sensitive to electric shock (static electricity, etc.). Due attention must be paid on charge of a human body and leakage from the equipment used.  
 2. Rated input/output frequency : 20MHz  
 3. \*  $t_{rr}$  measuring circuit

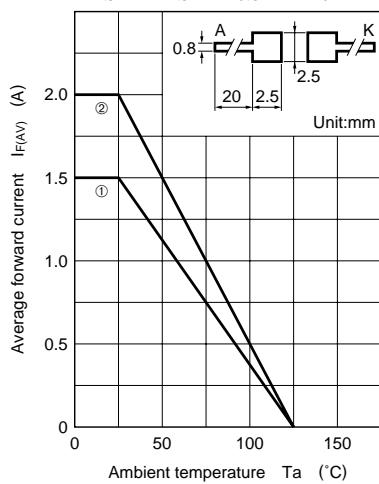
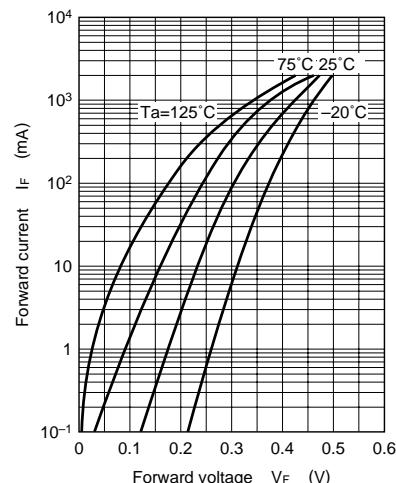
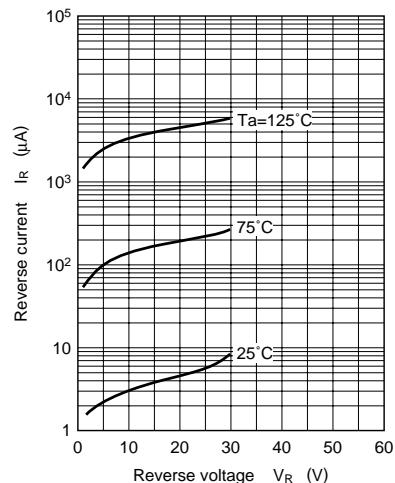
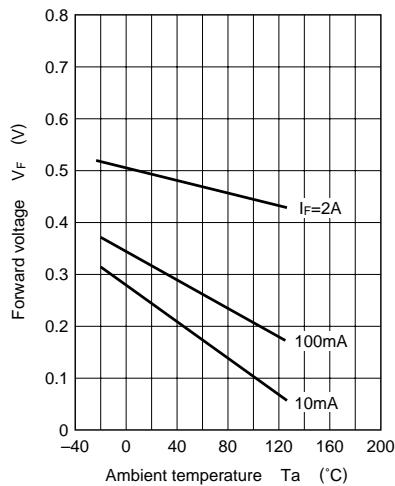
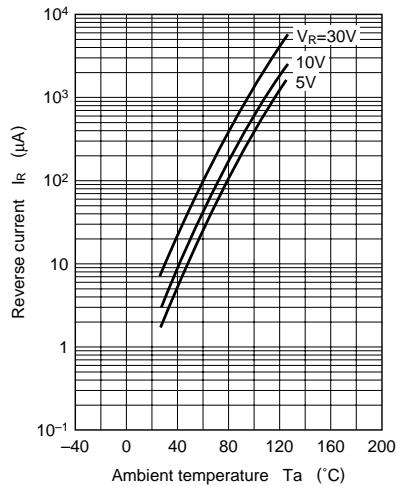


### ■ Marking



$I_{F(AV)} - Ta$ 

- ① Printed-circuit board : Glass epoxy board  
 ② Printed-circuit board : Alumina board  
 Copper foil for both A and K sides  
 $2.5\text{mm} \times 2.5\text{mm} + 0.8\text{mm} \times 20\text{mm}$

 $I_F - V_F$  $I_R - V_R$  $V_F - Ta$  $I_R - Ta$  $C_t - V_R$ 